

6N135/6N136

General Purpose Type Photocoupler

■ Features

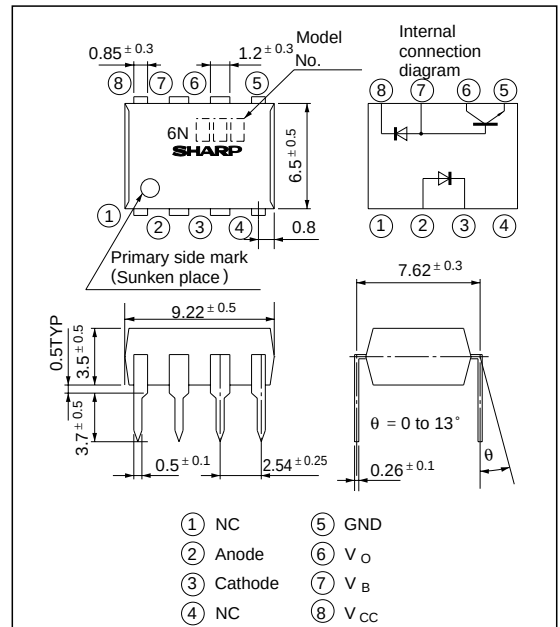
1. High speed response t_{PHL} , t_{PLH}
(**6N135** : MAX. $1.5\mu s$ at $R_L = 4.1k\Omega$)
(**6N136** : MAX. $0.8\mu s$ at $R_L = 1.9k\Omega$)
2. High common mode rejection voltage
(CM_H : TYP. $1kV/\mu s$)
3. Standard dual-in-line package
4. Recognized by UL, file No. E64380

■ Applications

1. Computers, measuring instruments, control equipment
2. High speed line receivers, high speed logic
3. Telephone sets
4. Signal transmission between circuits of different potentials and impedances

■ Outline Dimensions

(Unit : mm)



■ Absolute Maximum Ratings

(Ta = 25°C)

	Parameter	Symbol	Rating	Unit
Input	Forward current	I_F	25	mA
	*1 Peak forward current	I_F	50	mA
	*2 Peak transient forward current	I_{FM}	1	A
	Reverse voltage	V_R	5	V
	Power dissipation	P	45	mW
Output	Supply voltage	V_{CC}	- 0.5 to + 15	V
	Output voltage	V_O	- 0.5 to + 15	V
	Emitter-base reverse withstand voltage (Pin 5 to 7)	V_{EBO}	5	V
	Average output current	I_O	8	mA
	Peak output current	I_{OP}	16	mA
	Base current (Pin 7)	I_B	5	mA
	Power dissipation	P_O	100	mW
	*3 Isolation voltage	V_{iso}	2 500	V_{rms}
	Operating temperature	T_{opr}	- 55 to + 100	°C
	Storage temperature	T_{stg}	- 55 to + 125	°C
	*4 Soldering temperature	T_{sol}	260	°C

*1 50% duty cycle, Pulse width : 1ms

Decreases at the rate of $1.6mA/^{\circ}C$ if the external temperature is $70^{\circ}C$ or more.*2 Pulse width $\leq 1\mu s$, 300 p/s

*3 40 to 60% RH, AC for 1 minute

*4 For 10 seconds

* "OPIC" (Optical IC) is a trademark of the SHARP Corporation.

An OPIC consists of a light-detecting element and signal-processing circuit integrated onto a single chip.

■ Electro-optical Characteristics

(Ta = 0 to + 70 °C unless otherwise specified)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
*5 Current transfer ratio	6N135 CTR(1)	Ta = 25 °C, IF = 16mA	7.0	40	-	%
	6N136 CTR(1)	Vo = 0.4V, VCC = 4.5V	19	40	-	%
	6N135 CTR(2)	IF = 16mA, Vo = 0.5V	5.0	43	-	%
	6N136 CTR(2)	VCC = 4.5V	15	43	-	%
Logic (0) output voltage	VOL	*7IF = 16mA, VCC = 4.5V	-	0.1	0.4	V
Logic (1) output current	IOH(1)	Ta = 25 °C, IF = 0 VCC = Vo = 5.5V	-	3.0	500	nA
	IOH(2)	Ta = 25 °C, IF = 0 VCC = Vo = 15V	-	0.01	1.0	μA
	IOH(3)	IF = 0, VCC = Vo = 15V	-	-	50	μA
Logic (0) supply current	ICCL	IF = 16mA, VCC = 15V Vo = open	-	200	-	μA
Logic (1) supply current	ICCH(1)	Ta = 25 °C, VCC = 15V VF = open, IO = 0	-	0.02	1.0	μA
	ICCH(2)	VCC = 15V Vo = open, IF = 0	-	-	2.0	μA
Input forward voltage	VF	Ta = 25 °C, IF = 16mA	-	1.7	1.95	V
Input forward voltage temperature coefficient	ΔVF / ΔTa	IF = 16mA	-	-1.9	-	mV/°C
Input reverse voltage	BVR	Ta = 25 °C, IR = 10 μA	5.0	-	-	V
Input capacitance	CIN	VF = 0, f = 1MHz	-	60	-	pF
*6 Leak current (input-output)	II-O	Ta = 25 °C, 45 % RH, t = 5s VI-O = 3kVDC	-	-	1.0	μA
*6 Isolation resistance (input-output)	RI-O	VI-O = 500VDC	-	10 ¹²	-	Ω
*6 Capacitance (input-output)	CI-O	f = 1MHz	-	0.6	-	pF
Transistor current amplification factor	hFE	Vo = 5V, IO = 3mA	-	70	-	

*5 Current transfer ratio is the ratio of input current and output current expressed in % .

Note) Typical value : at Ta = 25 °C

*6 Measured as 2-pin element (Short 1, 2, 3, 4)

*7 **6N135** : IO = 1.1mA, **6N136** : IO = 2.4mA

■ Switching Characteristics

(Ta = 25 °C, V_{CC} = 5V, I_F = 16mA)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
*8 Propagation delay time Output (1)→(0)	6N135 t _{PHL}	R _L = 4.1kΩ	-	0.3	1.5	μ s
	6N136 t _{PHL}	R _L = 1.9kΩ	-	0.3	0.8	μ s
*8 Propagation delay time Output (0)→(1)	6N135 t _{PLH}	R _L = 4.1kΩ	-	0.4	1.5	μ s
	6N136 t _{PLH}	R _L = 1.9kΩ	-	0.3	0.8	μ s
*10,11 Instantaneous common mode rejection voltage “ output (1) ”	CM _H	*12 I _F = 0, V _{CM} = 10V _{P-P}	-	1 000	-	V/ μ s
*10,11 Instantaneous common mode rejection voltage “ output (0) ”	CM _L	*12 V _{CM} = 10V _{P-P} , I _F = 16mA	-	- 1 000	-	V/ μ s
*13 Bandwidth	BW	R _L = 100Ω	-	2.0	-	MHz

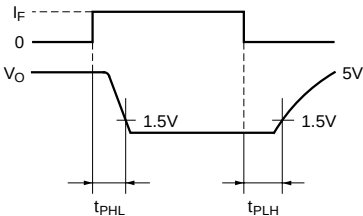
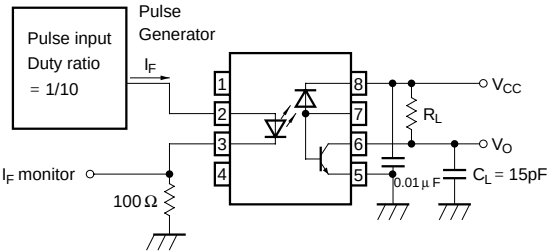
*8 R_L = 4.1k Ω is equivalent to one LSTTL and 6.1kΩ pull-up resistor. R_L=1.9kΩ is equivalent to one TTL and 5.6kΩ pull-up resistor.

*10 Instantaneous common mode rejection voltage “ output (1) ” represents a common mode voltage variation that can hold the output above (1) level (V_O > 2.0V).
Instantaneous common mode rejection voltage “ output (0) ” represents a common mode voltage variation that can hold the output above (0) level (V_O < 0.8V).

*12 **6N135**: R_L = 4.1k Ω **6N136**: R_L = 1.9kΩ

*13 Bandwidth represents a point where AC input goes down by 3dB.

*9 Test Circuit for Propagation Delay Time



*11 Test Circuit for Instantaneous Common Mode Rejection Voltage

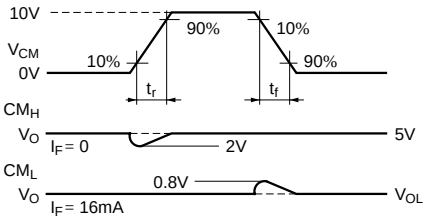
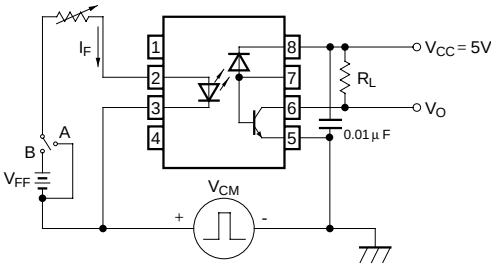


Fig. 1 Forward Current vs. Ambient Temperature

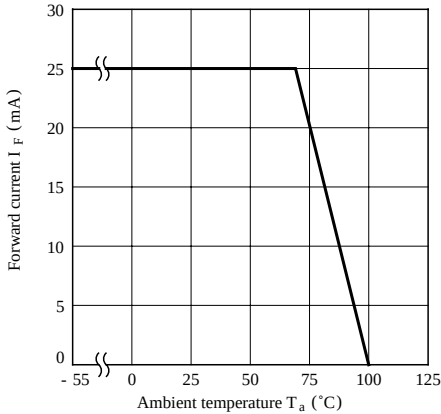


Fig. 2 Power Dissipation vs. Ambient Temperature

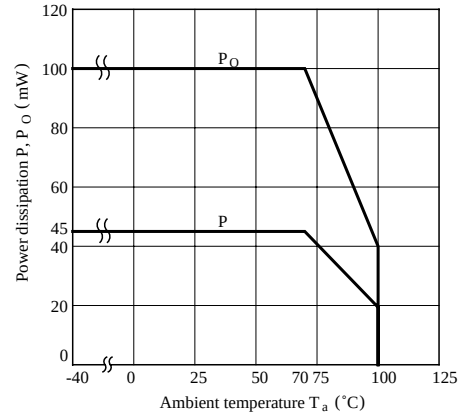


Fig. 3 Forward Current vs. Forward Voltage

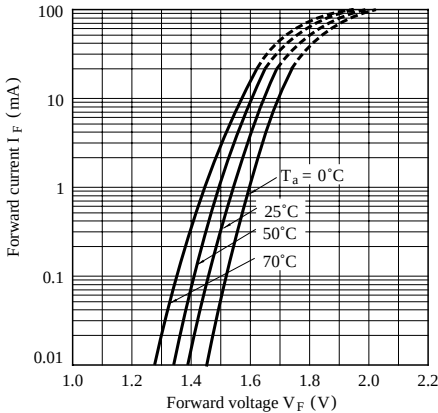


Fig. 4 Relative Current Transfer Ratio vs. Forward Current

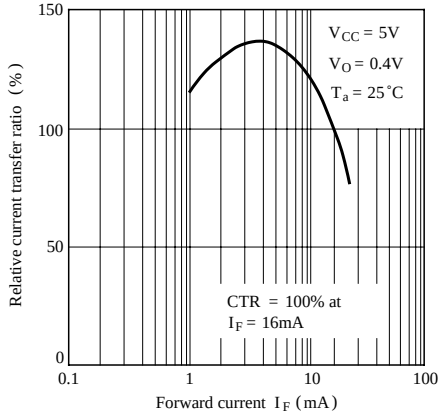


Fig. 5 Output Current vs. Output Voltage

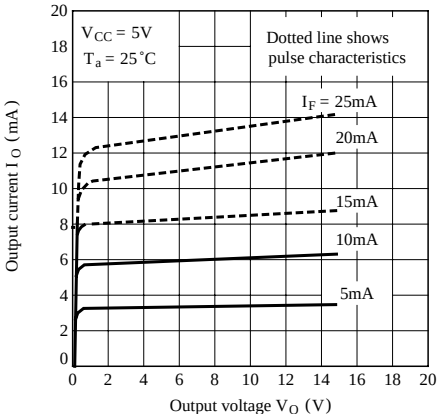


Fig. 6 Relative Current Transfer Ratio vs. Ambient Temperature

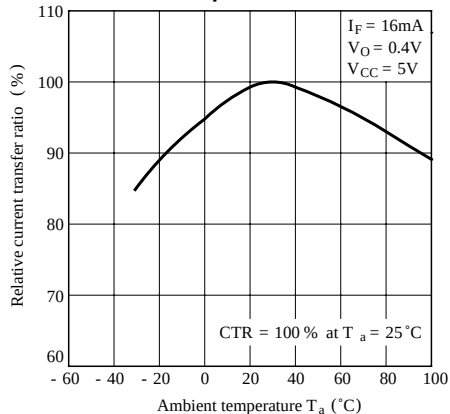


Fig. 7 Propagation Delay Time vs. Ambient Temperature

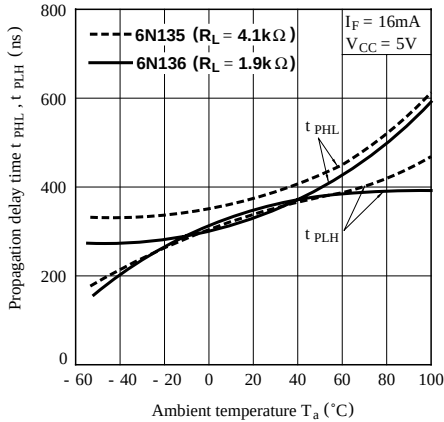


Fig. 8 High Level Output Current vs. Ambient Temperature

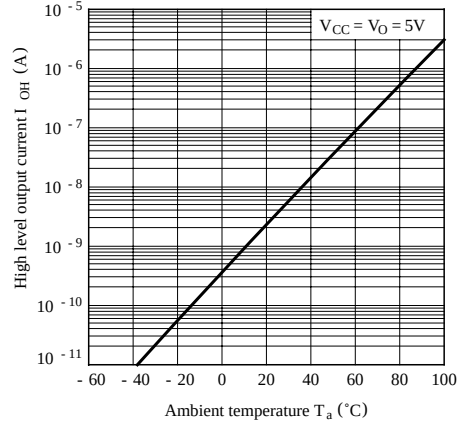
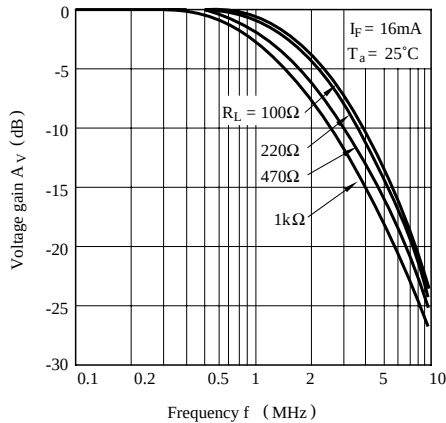
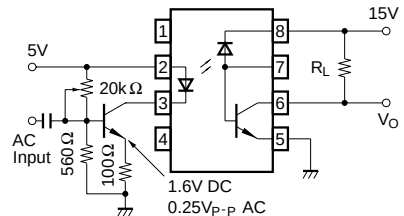


Fig. 9 Frequency Response



Test Circuit for Frequency Characteristic



■ Precautions for Use

- (1) It is recommended that a by-pass capacitor of more than $0.01\mu\text{F}$ be added between V_{CC} and GND near the device in order to stabilize power supply line.
 - (2) Transistor of detector side in bipolar configuration is apt to be affected by static electricity for its minute design. When handling them, general counterplan against static electricity should be taken to avoid breakdown of devices or degradation of characteristics.
- As for other general cautions, please refer to the chapter “ Precautions for Use ” .
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